IFW

| NIG 2 2 2005 | FOFFICE BY | IN THE UNITED STATES PAT | ENT A | ND TRADEMARK OFFICE |
|--------------------------------|------------|--------------------------|-------------|---------------------|
| FIANT & TRADENS | h re App | plication of: |) | |
| | | | : | |
| AKIRA UNNO | | |) | |
| | | | ; | |
| | Applicati | in No.: 10/517,529 : | | |
|] | Filed: Ju | me 19, 2003 | ;) : | |
| 371(c) Date: December 13, 2004 | | | ·) | |
| | | | : | |
|] | For: | ORGANIC SEMICONDUCTOR |) | |
| | | ELEMENT, PRODUCTION | : | |
| | | METHOD THEREFOR AND |) | |
| | | ORGANIC SEMICONDUCTOR | : | |
| | | DEVICE |) | August 19, 2005 |

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

In compliance with the duty of disclosure under 37 C.F.R. § 1.56 and in accordance with the practice under 37 C.F.R. §§ 1.97 and 1.98, the Examiner's attention is directed to the documents listed on the enclosed Form PTO-1449. Copies of the listed documents, other than U.S. patent documents, are enclosed.

JP 2001-94107 was cited in an international search report from which the subject application claims benefit of priority. A copy of the international search report is enclosed.

The following documents are discussed at the following pages of the specification:

| <u>Documents</u> | Page(s) |
|--|---------|
| U.S. Patent No. 5,596,208 | 3 |
| U.S. Patent No. 5,625,199 | 3 |
| U.S. Patent No. 5,574,291 | 3 |
| YY. Lin, et al., IEEE Transactions on Electron Devices | 4 |
| JP 7-206599 | 4 |
| JP 9-232589 | 5 |
| YY. Lin, et al., IEEE Electron Device Letters | 5 |
| JP 2001-94107 | 6 |
| R. B. Campbell, et al. | 41 |

English-language abstracts for JP 2001-94107, JP 9-232589 and JP 7-206599 are also enclosed.

According to a commercial database, U.S. Patent No. 6,326,640 is in the same family as JP 9-232589, and U.S. Patent Nos. 5,556,706 and 5,546,889 are in the same family as JP 7-206599.

The Examiner's attention is also directed to the following U.S. Application:

Application No. Filing Date Applicants

10/532,078 04/21/2005 A. Unno
N. Sato
H. Miyazaki
N. Doi

This Information Disclosure Statement is being filed before the issuance of a first Office Action on the merits. Therefore, no fee under 37 C.F.R. § 1.97(c)(2) is believed due. Nevertheless, the Commissioner may charge Deposit Account No. 06-1205, should any fee be due for filing this paper.

Applicant requests that the above information be considered by the Examiner and that a copy of the enclosed Form PTO-1449 be initialed and returned indicating that such information has been considered.

Applicant's undersigned attorney may be reached in our Costa Mesa,

California office at (714) 540-8700. All correspondence should continue to be directed to

our below-listed address.

Respectfully submitted,

Damond E. Vadnais Attorney for Applicant Registration No.: 52,310

FITZPATRICK, CELLA, HARPER & SCINTO 30 Rockefeller Plaza
New York, New York 10112-3800

| FORM PTO 1449 (modif | | | ATTY DOCKET NO. 03500.017331. | APPLICATION NO. 10/517,529 | | | | | | | |
|----------------------|---|-----------------|--|----------------------------|---|---------------------------------------|--|--|--|--|--|
| LIST OF REI | DEPARTMENT OF COMMERCE INT AND TRADEMARK OFFICE FERENCES CITED BY APPLIC | CANT(S) | APPLICANT AKIRA UNNO | | | | | | | | |
| | e several sheets if nedessary) All | 8 2 2 2005 E | FILING DATE June 19, 200 | GROUP | | | | | | | |
| | P. P. C. | TE YRAUGHARE | U.S. PATENT DOCUMENTS | | | | | | | | |
| *EXAMINER INITIAL | DOCUMENT NUMBER | DATE | NAME | CLASS | SUBCLASS | FILING DATE | | | | | |
| | 6,783,588 | 8/31/04 | Aoto, et al. | 117 | 4 | *** | | | | | |
| | 6,326,640 | 12/04/01 | Shi, et al. | 257 | 40 | | | | | | |
| | 5,625,199 | 4/29/97 | Baumbach, et al. | 257 | 40 | | | | | | |
| | 5,596,208 | 1/21/97 | Dodabalapur, et al. | 257 | 66 | | | | | | |
| | 5,574,291 | 11/12/96 | Dodabalapur, et al. | 257 | 40 | | | | | | |
| | 5,556,706 | 9/17/96 | Wakita, et al. | 428 | 421 | | | | | | |
| | 5,546,889 | 8/20/96 | Wakita, et al. | 117 | 84 | | | | | | |
| | 2004-0231581 | 11/25/04 | Aoto, et al. | 117 | 2 | | | | | | |
| | | - | | | | | | | | | |
| | | | | | | | | | | | |
| | | | | | | | | | | | |
| | | FC | PREIGN PATENT DOCUMENTS | | r · · · · · · · · · · · · · · · · · · · | | | | | | |
| | DOCUMENT NUMBER | DATE | COUNTRY | CLASS | SUBCLASS | TRANSLATION YES/NO/ OR ABSTRACT | | | | | |
| | 2001-94107 | 4/06/01 | Japan | | | Abstract | | | | | |
| | 9-232589 | 5/09/97 | Japan | | | Abstract | | | | | |
| | 7-206599 | 8/08/95 | Japan | | | Abstract | | | | | |
| | | | | | | | | | | | |
| | 0 | THER DOCUMENT(S |) (Including Author, Title, Date, Pertinen | t Pages, Etc.) | | | | | | | |
| | Campbell, R. B, et al., "The Crystal and Molecular Structure of Pentacene", <i>Acta Cryst.</i> , Vol. 14, (1961) pp. 705-711. | | | | | | | | | | |
| | Lin, YY., et al. "Stacked Pentacene Layer Organic Thin-Film Transistors with Improved Characteristics", <i>IEEE Electron Device Letters</i> , Vol. 18, No. 12, (Dec. 1997) pp. 606-608. | | | | | | | | | | |
| | Lin, YY., "Pentacene-Based Organic Thin-film Transistors", <i>IEEE Transactions on Electron Devices</i> , Vol. 44, No. 8, (Aug. 1997) pp. 1325-1331. | | | | | | | | | | |
| | | | | | | • | | | | | |
| EXAMINER | EXAMINER DATE CONSIDERED | | | | | | | | | | |

Sheet_1_ of _1_

^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.